

Vishay Semiconductors

Small Signal Schottky Diodes

Features

- Integrated protection ring against static discharge
- Low capacitance
- · Low leakage current
- Low forward voltage drop
- AEC-Q101 qualified
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC









Applications

- HF-Detector
- · Protection circuit
- · Small battery charger
- AC-DC / DC-DC converters

Mechanical Data

Case: QuadroMELF SOD-80
Weight: approx. 34 mg
Cathode band color: black
Packaging codes/options:

GS18 / 10 k per 13" reel (8 mm tape), 10 k/box GS08 / 2.5 k per 7" reel (8 mm tape), 12.5 k/box

Parts Table

Part	Type differentiation	Ordering code	Remarks	
LS103A	V _R = 40 V	LS103A-GS18 or LS103A-GS08	Tape and Reel	
LS103B	V _R = 30 V	LS103B-GS18 or LS103B-GS08	Tape and Reel	
LS103C	V _R = 20 V	LS103C-GS18 or LS103C-GS08	Tape and Reel	

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Part	Symbol	Value	Unit	
		LS103A	V _R	40	V	
Reverse voltage		LS103B	V _R	30	V	
		LS103C	V _R	20	V	
Peak forward surge current	t _p = 300 μs, square pulse		I _{FSM}	15	Α	
Power dissipation			P _{tot}	400	mW	

Thermal Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit	
Thermal resistance junction to ambient air	On PC board 50 mm x 50 mm x 1.6 mm	R _{thJA}	250	K/W	
Junction temperature		Tj	125	°C	
Storage temperature range		T _{stg}	- 65 to + 150	°C	

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For technical questions within your region, please contact one of the following: DiodesAmericas@vishav.com, DiodesAsia@vishav.com, DiodesEurope@vishav.com

LS103A, LS103B, LS103C

Vishay Semiconductors



Electrical Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Part	Symbol	Min	Тур.	Max	Unit
Reverse Breakdown Voltage	I _R = 10 μA	LS103A	V _(BR)	40			V
		LS103B	V _(BR)	30			V
		LS103C	V _(BR)	20			V
Leakage current	V _R = 30 V	LS103A	I _R			5	μΑ
	V _R = 20 V	LS103B	I _R			5	μΑ
	V _R = 10 V	LS103C	I _R			5	μΑ
Forward voltage drop	I _F = 20 mA		V _F			370	mV
	I _F = 200 mA		V _F			600	mV
Diode capacitance	V _R = 0 V, f = 1 MHz		C _D		50		pF
Reverse recovery time	$I_F = I_R = 50 \text{ to } 200 \text{ mA},$ recover to 0.1 I_R		t _{rr}		10		ns

Typical Characteristics

T_{amb} = 25 °C, unless otherwise specified

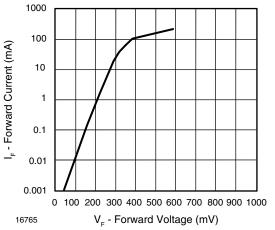


Figure 1. Forward Current vs. Forward Voltage

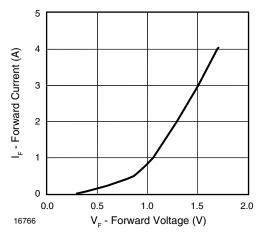


Figure 2. Forward Current vs. Forward Voltage

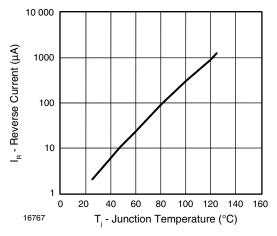


Figure 3. Reverse Current vs. Junction Temperature

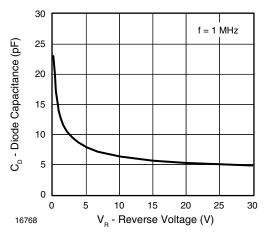


Figure 4. Diode Capacitance vs. Reverse Voltage

Vishay Semiconductors

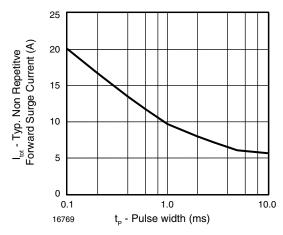
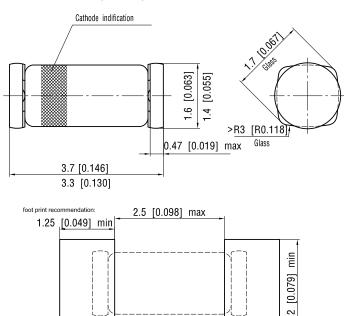


Figure 5. Typ. Non Repetitive Forward Surge Current vs.
Pulse width

Package Dimensions in millimeters (inches): QuadroMELF SOD-80



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